

4.5Ω 300MHz Bandwidth Dual SPDT Analog Switch UM4258Q QFN10 1.80×1.40

General Description

The UM4258Q low-voltage, low on-resistance (R_{ON}), dual single-pole/double-throw (SPDT) analog switch operates from a single +1.8V to +5.5V supply. The device is designed for USB 1.1/2.0 and audio switching applications.

The UM4258Q features two 4.5 Ω R_{ON}(max) SPDT switches with 1.2 Ω flatness and 0.3 Ω matching between channels. The switch offers break-before-make switching (1ns) with t_{ON}<80ns and t_{OFF}<40ns at +2.7V. The digital logic inputs are +1.8V logic compatible with a +2.7V to +3.6V supply.

The UM4258Q is packaged in a 1.80mm×1.40mm QFN10 package, which significantly reducing the required PC board area.

Applications

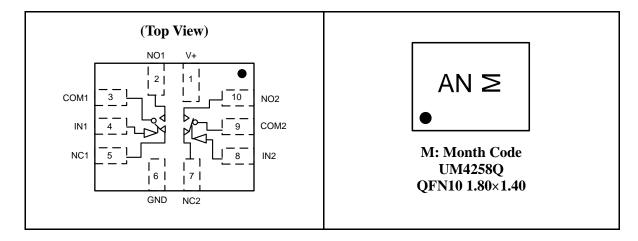
- USB 1.1/2.0 Signal Switching Circuits
- Battery-Operated Equipment
- Audio/Video-Signal Routing
- Headphone Switching
- Low-Voltage Data-Acquisition Systems
- Sample-and-Hold Circuits
- Cell Phones
- PDAs

Features

- 2ns (Max) Differential Skew
- -3dB Bandwidth: 300MHz
- Low 15pF On-Channel Capacitance
- Single-Supply Operation from +1.8V to +5.5V
- 4.5Ω R_{ON} (Max) Switches
 0.3Ω (Max) R_{ON} Match (+3.0V Supply)
 1.2Ω (Max) Flatness (+3.0V Supply)
- Rail-to-Rail Signal Handling
- High Off-Isolation: -55dB (10MHz)
- Low Crosstalk: -80dB (10MHz)
- Low Distortion: 0.03%
- +1.8V CMOS-Logic Compatible
- < 0.5nA Leakage Current at +25°C

Pin Configurations

Top View





Pin Description

Pin Number	Name	Function			
7	NC2	Analog Switch 2-Normally Closed Terminal			
8	IN2	Analog Switch 2-Digital Control Input			
9	COM2	Analog Switch 2-Common Terminal			
10	NO2	Analog Switch 2-Normally Open Terminal			
6	GND	Ground Connection			
1	V_{+}	Positive Supply Voltage			
5	NC1	Analog Switch 1-Normally Closed Terminal			
4	IN1	Analog Switch 1-Digital Control Input			
3	COM1	Analog Switch 1-Common Terminal			
2	NO1	Analog Switch 1-Normally Open Terminal			

Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM4258Q	QFN10 1.80×1.40	AN	3000pcs/7 Inch Tape & Reel

Function Table

IN_	NO_	NC_
0	OFF	ON
1	ON	OFF

Absolute Maximum Ratings

Symbol	Parameter		Limit	Unit
V_{+}	Supply Voltage		-0.3 to +6.0	
V_{S}	DC Switch Voltage (Note 1)		-0.3 to $(V_{+}+0.3)$	V
IN_	DC IN Voltage		-0.3 to +6.0	
Io	Continuous Current (COM_, NO	_, NC_)	±100	A
I_{P}	Peak Current (Pulsed at 1ms, 10%	±200	mA	
T_{O}	Operating Temperature Range	-40 to +85		
T_{J}	Junction Temperature		+150	
T_{STG}	Storage Temperature Range		-65 to +150	°C
$T_{ m L}$	Junction Lead Temperature (Sold	lering, 10 Seconds)	+300	C
Т	Duran Tanananatuna (Caldania a)	Infrared (15s)	+220	
1 Bump	T_{Bump} Bump Temperature (Soldering) Vapor I		+215	
P _D	Continuous Power Dissipation @ +70°C		909	mW
ESD	ESD Method 3015.7		>2000	V

Note 1: Signals on COM_, NO_, or NC_ exceeding V₊ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.



DC Electrical Characteristics (Single +3V Supply)

(V₊=+2.7V to +3.6V, V_{IH}=+1.4V, V_{IL}=+0.5V, $T_A=T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at V₊=+3.0V, T_A =+25°C) (Note 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (-40°C to 85°C)			Unit		
Symbol	Turumeter	Test Conditions	Temp	Min	Тур	Max	Cint		
DC Electi	DC Electrical Characteristics								
$egin{array}{c} V_{COM_} \ V_{NO_} \ V_{NC_} \end{array}$	Analog Signal Range		Full	0		V_{+}	V		
V_{+}	Power Supply Range		Full	1.8		5.5	V		
I_{+}	Supply Current	$V_{+}=+5.5V$, $V_{IN}=0V$ or V_{+}	Full			1	μΑ		
I _{COM_(ON)}	COM_On Leakage Current (Note 7)	V_{+} =+3.6V, V_{COM} =0.3V, 3.3V; V_{NO} or V_{NC} =0.3V, 3.3V, or Floating	Room Full	-1 -2	+0.01	+1 +2	nA		
I_{OFF}	OFF State Leakage Current (Note 7)	$V_{+}=+3.6V,$ $V_{COM_{-}}=0.3V, 3.3V;$ $V_{NO_{-}}$ or $V_{NC_{-}}=3.3V, 0.3V$	Room Full	-0.5 -1	+0.01	+0.5 +1	nA		
V_{IH}	Input High Voltage		Full	1.4			V		
$V_{\rm IL}$	Input Low Voltage		Full			0.5	V		
I _{IN}	Input Leakage Current	$V_{+}=+3.6V$, $V_{IN}=0$ or 5.5V	Full	-100		+100	nA		
D	On-Resistance	$V_{+}=+2.7V, I_{COM}=10mA;$	Room		3.0	4.5	Ω		
R _{ON}	(Note 4)	$V_{NO_{-}}$ or $V_{NC_{-}}=1.5V$	Full			5			
AD	On Resistance Match Between Channels	V ₊ =+2.7V, I _{COM} _=10mA;	Room		0.1	0.3	Ω		
ΔR_{ON}	(Note 4, 5)	$V_{NO_{-}}$ or $V_{NC_{-}}=1.5V$	Full			0.4	2.2		
R_{FLAT}	On Resistance Flatness	V ₊ =+2.7V, I _{COM} _=10mA; V _{NO} _ or V _{NC} _=1.0V, 1.5V,	Room		0.6	1.2	Ω		
FLAT	(Note 6)	2.0V	Full			1.5	32		



AC Electrical Characteristics (Single +3V Supply) (V₊=+2.7V to +3.6V, V_{IH}=+1.4V, V_{IL}=+0.5V, T_A=T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V₊=+3.0V, T_A=+25°C) (Note 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (-40°C to 85°C)			Unit	
<i>5</i> 3 222 61	1 W1 W1110001	2450 COMMINIONS	101111	Min	Тур	Max		
AC Electr	AC Electrical Characteristics							
t _{ON}	Turn-On Time	$V_{NO_{-}}, V_{NC_{-}}=1.5V;$ $R_{L}=300\Omega, C_{L}=35pF, Figure 1;$ $V_{IH}=1.5V, V_{IL}=0V$	Room Full		40	80 100	ns	
$t_{ m OFF}$	Turn-Off Time	$V_{NO_{-}}, V_{NC_{-}}=1.5V;$ $R_{L}=300\Omega, C_{L}=35pF, Figure 1;$ $V_{IH}=1.5V, V_{IL}=0V$	Room Full		20	40 50	ns	
$t_{ m BBM}$	Break Before Make Time (Note 7)	$V_{NO_}$, $V_{NC_}$ =1.5V; R_L =300 Ω , C_L =35pF, Figure 2	Room Full	1	8		ns	
t_{SKEW}	Skew (Note 7)	R_S =39 Ω , C_L =50pF, Figure 3	Full		0.15	2	ns	
Q _{INJ}	Charge Injection	C_L =1.0nF, Figure 4 V_{GEN} =1.5V, R_{GEN} =0 Ω	Room		5		pC	
V	Off Lasterian	$\begin{array}{c} f=10MHz;\\ V_{NO_},V_{NC_}=1V_{P-P};\\ R_L=50\Omega,C_L=5pF,Figure\;5 \end{array}$	D		-55		dB	
V _{ISO}	Off Isolation	$\begin{array}{c} \text{f=1MHz;} \\ V_{\text{NO}_{-}}, V_{\text{NC}_{-}} = 1 V_{\text{P-P}}; \\ R_{\text{L}} = 50\Omega, C_{\text{L}} = 5 \text{pF, Figure 5} \end{array}$	Room		-80		цБ	
V_{CT}	Crosstalk (Note 8)	$\begin{array}{c} f=10MHz;\\ V_{NO_},V_{NC_}=1V_{P-P};\\ R_L=50\Omega,C_L=5pF,Figure\;5 \end{array}$	Room		-80		dB	
▼ CT	Clossialk (Note 6)	$\begin{array}{c} \text{f=1MHz;} \\ V_{\text{NO}_{-}}, V_{\text{NC}_{-}} = 1 V_{\text{P-P}}; \\ R_{\text{L}} = 50 \Omega, C_{\text{L}} = 5 \text{pF, Figure 5} \end{array}$	Room		-110		uБ	
BW	-3dB Bandwidth	Signal=0dBm, R_L =50 Ω , C_L =5pF, Figure 5	Room		300		MHz	
THD	Total Harmonic Distortion	R_L =600 Ω , V_{COM} =2 V_{P-P}	Room		0.03		%	
Capacitan	ace							
$C_{NO_(OFF)}$ $C_{NC_(OFF)}$	NO_, NC_ Off Capacitance	f=1MHz, Figure 6	Room		9		pF	
C _(ON)	Switch On Capacitance	f=1MHz, Figure 6	Room		15		pF	



DC Electrical Characteristics (Single +5V Supply) (V_+ =+4.2V to +5.5V, V_{IH} =+2.0V, V_{IL} =+0.8V, T_A = T_{MIN} to T_{MAX} , unless otherwise noted. Typical values are at V_+ =+5.0V, T_A =+25°C) (Note 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (-40°C to 85°C)			Unit		
Sy 1110 01	- W-W-11000	2000 001141110115	Tomp	Min	Тур	Max	0.111		
DC Electi	DC Electrical Characteristics								
$egin{array}{c} V_{COM} \ V_{NO} \ V_{NC} \end{array}$	Analog Signal Range		Full	0		V_{+}	V		
$V_{\scriptscriptstyle +}$	Power Supply Range		Full	1.8		5.5	V		
I_{+}	Supply Current	$V_{+}=+5.5V$, $V_{IN}_{-}=0V$ or V_{+}	Full			1	μΑ		
I _{COM_(ON)}	COM_On Leakage Current (Note 7)	V_{+} =+5.5V, V_{COM} =1.0V, 4.5V; V_{NO} or V_{NC} =1.0V, 4.5V, or Floating	Room Full	-1 -2	+0.01	+1 +2	nA		
I_{OFF}	OFF State Leakage Current (Note 7)	V_{+} =+5.5V, $V_{COM_{-}}$ =1.0V, 4.5V; $V_{NO_{-}}$ or $V_{NC_{-}}$ =1.0V, 4.5V	Room Full	-0.5 -1	+0.01	+0.5 +1	nA		
V_{IH}	Input High Voltage		Full	2.0			V		
$V_{\rm IL}$	Input Low Voltage		Full			0.8	V		
I _{IN}	Input Leakage Current	$V_{+}=+5.5V$, $V_{IN}_{-}=0$ or V_{+}	Full	-100		+100	nA		
D	On-Resistance	$V_{+}=+4.2V, I_{COM}=10mA;$	Room		1.7	3	Ω		
R_{ON}	(Note 4)	$V_{NO_{-}}$ or $V_{NC_{-}}=3.5V$	Full			3.5			
$\Delta R_{ m ON}$	On Resistance Match Between Channels	V ₊ =+4.2V, I _{COM} _=10mA;	Room		0.1	0.3	Ω		
ΔICON	(Note 4, 5)	$V_{NO_{-}}$ or $V_{NC_{-}}$ =3.5V	Full			0.4	22		
R_{FLAT}	On Resistance Flatness	V ₊ =+4.2V, I _{COM} _=10mA; V _{NO} _ or V _{NC} _=1.0V, 2.0V,	Room		0.4	1.2	Ω		
**FLA1	(Note 6)	3.5V	Full			1.5	-5		



AC Electrical Characteristics (Single +5V Supply)

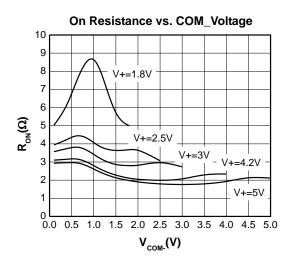
(V₊=+4.2V to +5.5V, V_{IH}=+2.0V, V_{IL}=+0.8V, T_A=T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V₊=+5.0V, T_A=+25°C) (Note 2, 3)

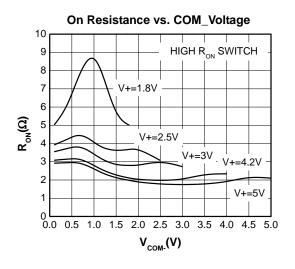
Symbol	Parameter	Test Conditions	Temp	Limits (-40°C to 85°C)			Unit
0,11001	2 42 42	2 000 0 0 1 0 1 0 1 0 1	10111	Min	Тур	Max	
AC Electr	ical Characteristics						
t _{ON}	Turn-On Time	$V_{NO_}$, $V_{NC_}$ =3.0V; R_L =300 Ω , C_L =35pF, Figure 1;	Room Full		30	80 100	ns
t _{OFF}	Turn-Off Time	$V_{NO_}$, $V_{NC_}$ =3.0V; R_L =300 Ω , C_L =35pF, Figure 1;	Room Full		20	40 50	ns
t _{BBM}	Break Before Make Time (Note 7)	V_{NO} , V_{NC} =3.0V; R_L =300 Ω , C_L =35pF, Figure 2	Room Full	1	8		ns
t _{SKEW}	Skew (Note 7)	R_S =39 Ω , C_L =50pF, Figure 3	Full		0.15	2	ns
Q _{INJ}	Charge Injection	C_L =1.0nF, Figure 4 V_{GEN} =1.5V, R_{GEN} =0 Ω	Room		9		pC
$ m V_{ISO}$	Off Isolation	$\begin{array}{c} f=10MHz;\\ V_{NO_},V_{NC_}=1V_{P-P};\\ R_L=50\Omega,C_L=5pF,Figure\;5 \end{array}$	Room		-55		dB
V ISO	On isolation	$\begin{array}{c} f{=}1MHz;\\ V_{NO_}, V_{NC_}{=}1V_{P{-}P};\\ R_{L}{=}50\Omega, C_{L}{=}5pF, Figure~5 \end{array}$	Room		-80		
V_{CT}	Crosstalk (Note 8)	$\begin{array}{c} f=10MHz;\\ V_{NO_},V_{NC_}=1V_{P-P};\\ R_L=50\Omega,C_L=5pF,Figure\;5 \end{array}$	Room		-80		dB
V CT	Crosstalk (Note 8)	$\begin{array}{c} f{=}1MHz;\\ V_{NO_}, V_{NC_}{=}1V_{P{-}P};\\ R_{L}{=}50\Omega, C_{L}{=}5pF, Figure~5 \end{array}$	Room		-110		uБ
BW	-3dB Bandwidth	Signal=0dBm, R_L =50 Ω , C_L =5pF, Figure 5	Room		300		MHz
THD	Total Harmonic Distortion	R_L =600 Ω , V_{COM} =2 V_{P-P}	Room		0.03		%
Capacitan	nce		_		-	_	_
$\begin{array}{c} C_{NO_(OFF)} \\ C_{NC_(OFF)} \end{array}$	NO_, NC_ Off Capacitance	f=1MHz, Figure 6	Room		9		pF
C _(ON)	Switch On Capacitance	f=1MHz, Figure 6	Room	1 '	15		pF

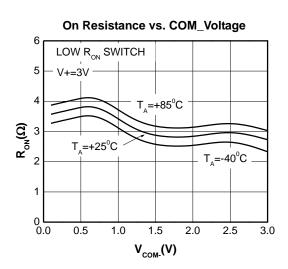
- Note 2: The parts are 100% tested at +25°C only, and guaranteed by design over the specified temperature range.
- Note 3: The algebraic convention used in this data sheet is where the most negative value is a minimum and the most positive value is a maximum.
- Note 4: Guaranteed by design.
- Note 5: $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.
- Note 7: Guaranteed by design.
- Note 8: Between any two switches.

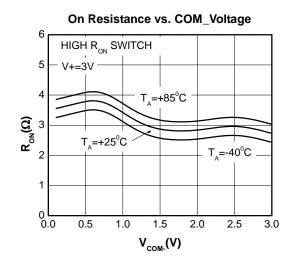


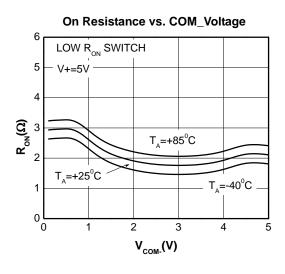
Typical Operating Characteristics

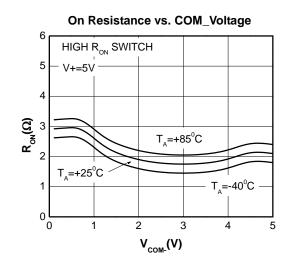






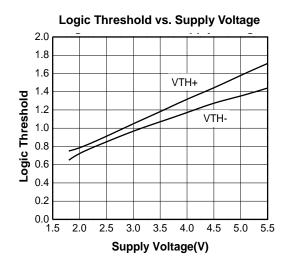


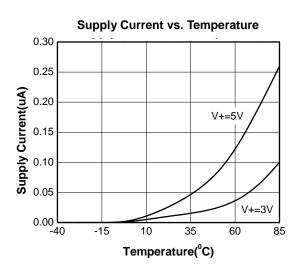


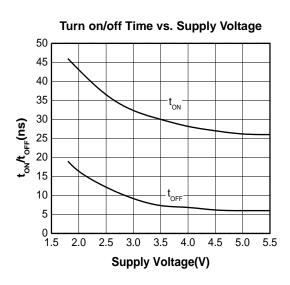


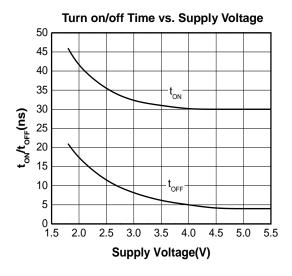


Typical Operating Characteristics (Continued)



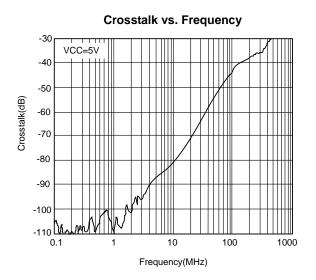


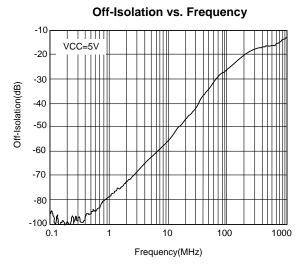


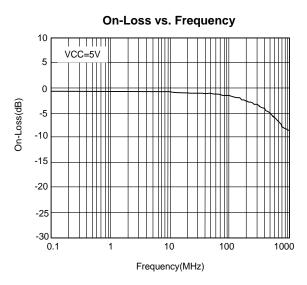




Typical Operating Characteristics (Continued)









Detailed Description

The UM4258Q high-speed, low-voltage, low on-resistance (R_{ON}), dual SPDT analog switch operates from a single +1.8V to +5.5V supply. The switch features break-before-make switching operation and fast switching speeds (t_{ON} =80ns (max), t_{OFF} =40ns (max)).

The switch has low 15pF on-channel capacitance, which allows for 12Mbps switching of the data signals for USB 1.0/1.1 applications. The UM4258Q is designed to switch D_+ and D_- USB signals with a guaranteed skew of less than 2ns (see Figure 4) as measured from 50% of the input signal to 50% of the output signal.

Applications Information

Digital Control Inputs

The UM4258Q logic inputs accept up to +5.5V regardless of supply voltage. For example, with a +3.3V supply, IN_ can be driven low to GND and high to +5.5V allowing for mixing of logic levels in a system. Driving the control logic inputs rail-to-rail minimizes power consumption. For a +3V supply voltage, the logic thresholds are 0.5V (low) and 1.4V (high); for a +5V supply voltage, the logic thresholds are 0.8V (low) and 2.0V (high).

Analog Signal Levels

The on-resistance of the UM4258Q changes very little for analog input signals across the entire supply voltage range (see the Typical Operating Characteristics). The switches are bidirectional, so the NO_, NC_, and COM_ pins can be either inputs or outputs.

Power-Supply Sequencing and Over-Voltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V_+ before applying analog signals, especially if the analog signal is not current-limited.

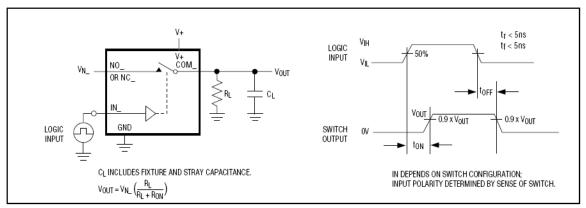


Figure 1. Switching Time

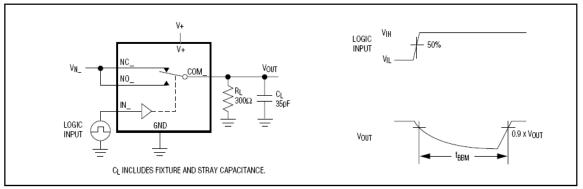


Figure 2. Break-Before-Make Interval



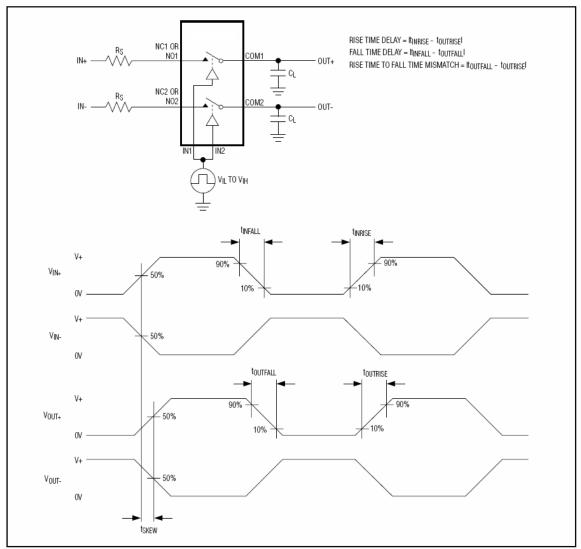


Figure 3. Output Signal Skew

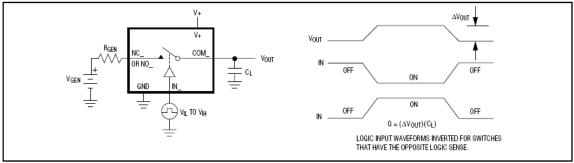


Figure 4. Charge Injection



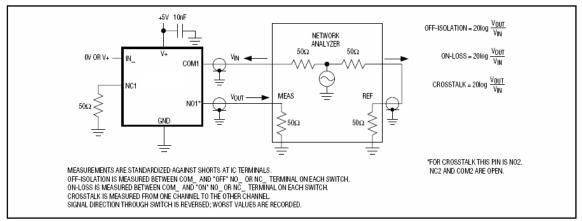


Figure 5. On-Loss, Off-Isolation, and Crosstalk

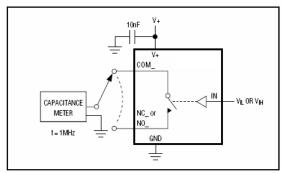


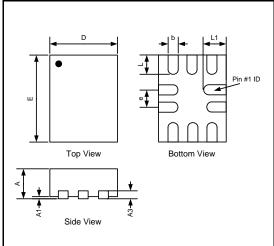
Figure 6. Channel Off/On-Capacitance



Package Information

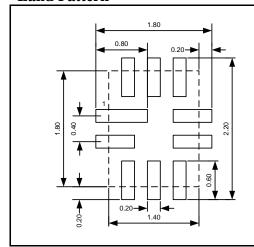
UM4258Q: QFN10 1.80×1.40

Outline Drawing



DIMENSIONS							
Crmbal	MIL	LIME	TERS]	3		
Symbol	Min	Тур	Max	Min	Тур	Max	
A	0.50	0.55	0.60	0.020	0.022	0.024	
A1	0.00	-	0.05	0.000	-	0.002	
A3	0.15REF			0.006REF			
b	0.15	0.20	0.25	0.006	0.008	0.010	
D	1.35	1.40	1.45	0.053	0.055	0.057	
Е	1.75	1.80	1.85	0.069	0.071	0.073	
e	0.40BSC			0.016BSC			
L	0.30	0.40	0.50	0.012	0.016	0.020	
L1	0.40	0.50	0.60	0.016	0.020	0.024	

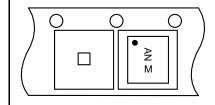
Land Pattern



NOTES:

- 1. Compound dimension: 1.80×1.40;
- 2. Unit: mm
- 3. General tolerance ± 0.05 mm unless otherwise specified;
- 4. The layout is just for reference.

Tape and Reel Orientation





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